

Vishay General Semiconductor

High Current Density Surface Mount Schottky Barrier Rectifiers



PRIMARY CHARACTERISTICS			
I _{F(AV)}	2 x 6.0 A		
V _{RRM}	40 V		
I _{FSM}	150 A		
E _{AS}	20 mJ		
V _F at I _F = 1.0 A	0.24 V		
T _J max.	125 °C		

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and protection applications.

FEATURES

· Very low profile - typical height of 1.1 mm



· Ideal for automated placement

 Low forward voltage drop, low power losses

RoHS HALOGEN

FREE

High efficiency

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · AEC-Q101 qualified
- · Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability

Base P/N-M3 - halogen-free and RoHS compliant,

commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

PARAMETER	SYMBOL	SS12P4C	UNIT
Device marking code		S124C	
Maximum repetitive peak reverse voltage	V_{RRM}	40	V
Maximum average forward rectified current (fig. 1) (1) total device per diode	I _{F(AV)} 12 6.0		А
Maximum average forward rectified current (2) total device	I _{F(AV)}	3.5	Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150	А
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E _{AS}	20	mJ
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, at T_J = 25 °C per diode	I _{RRM}	1.0	А
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 125	°C

Notes

⁽¹⁾ Mounted on 30 mm x 30 mm Al P.C.B. with 50 mm x 25 mm x 100 mm fin heat sink

⁽²⁾ Free air, mounted on recommended copper pad area

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode (1)	I _F = 1 A I _F = 3 A I _F = 6 A	T _A = 25 °C	V _F	0.34 0.40 0.46	- - 0.52	· V
	$I_F = 1 A$ $I_F = 3 A$ $I_F = 6 A$	T _A = 100 °C		0.24 0.31 0.40	- - 0.45	
Reverse current per diode per diode (2)	Rated V _R	T _A = 25 °C T _A = 100 °C	I _R	129 11.9	500 25	μA mA
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	400	-	pF

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER SYMBOL SS12P4C				
Typical thermal resistance per device	R _{θJA} ⁽¹⁾ R _{θJM} ⁽²⁾	100 3	°C/W	

Notes

 $^{(1)}$ Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient.

Mounted on 30 mm x 30 mm Al P.C.B. with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance $R_{\theta JM}$ - junction to mount.

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	
SS12P4CHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4CHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel	

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

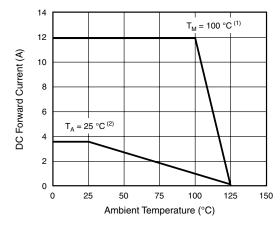


Figure 1. Maximum Forward Current Derating Curve

Notes

- ⁽¹⁾ Mounted on 30 mm x 30 mm Al P.C.B. with 50 mm x 25 mm x 100 mm fin heat sink, T_M measured at the terminal of cathode band $(R_{A,IM} = 3 \text{ °C/W})$
- band ($R_{\theta JM} = 3 \, ^{\circ}C/W$) (2) Free air, mounted on recommended copper pad area ($R_{\theta JA} = 100 \, ^{\circ}C/W$)

⁽¹⁾ AEC-Q101 qualified



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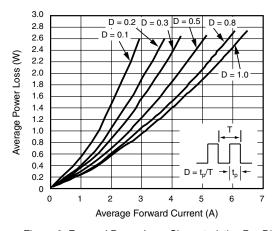


Figure 2. Forward Power Loss Characteristics Per Diode

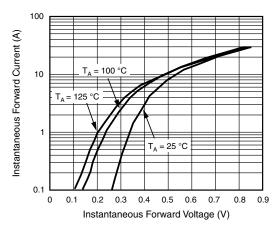


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

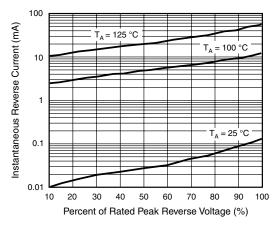


Figure 4. Typical Reverse Leakage Characteristics Per Diode

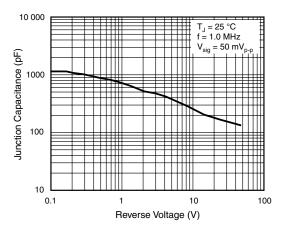


Figure 5. Typical Junction Capacitance Per Diode

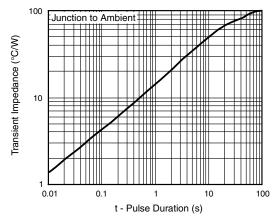
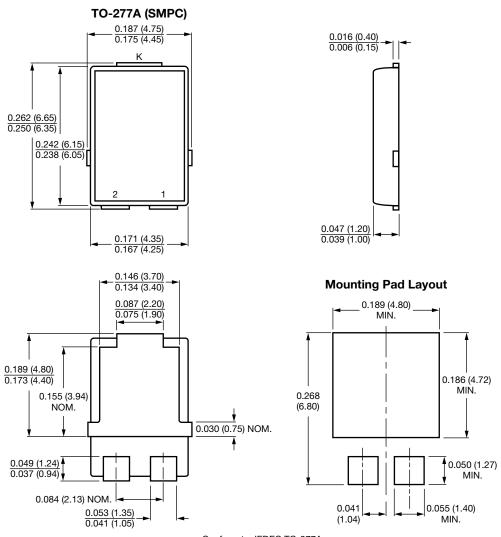


Figure 6. Typical Transient Thermal Impedance Per Device

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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